

## MC33201, MC33202, MC33204, NCV33202

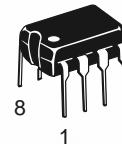
### Low Voltage, Rail-to-Rail Operational Amplifiers

The MC33201/2/4 family of operational amplifiers provide rail-to-rail operation on both the input and output. The inputs can be driven as high as 200 mV beyond the supply rails without phase reversal on the outputs, and the output can swing within 50 mV of each rail. This rail-to-rail operation enables the user to make full use of the supply voltage range available. It is designed to work at very low supply voltages ( $\pm 0.9$  V) yet can operate with a supply of up to +12 V and ground. Output current boosting techniques provide a high output current capability while keeping the drain current of the amplifier to a minimum. Also, the combination of low noise and distortion with a high slew rate and drive capability make this an ideal amplifier for audio applications.

- Low Voltage, Single Supply Operation (+1.8 V and Ground to +12 V and Ground)
- Input Voltage Range Includes both Supply Rails
- Output Voltage Swings within 50 mV of both Rails
- No Phase Reversal on the Output for Over-driven Input Signals
- High Output Current ( $I_{SC} = 80$  mA, Typ)
- Low Supply Current ( $I_D = 0.9$  mA, Typ)
- $600\ \Omega$  Output Drive Capability
- Extended Operating Temperature Ranges (-40° to +105°C and -55° to +125°C)
- Typical Gain Bandwidth Product = 2.2 MHz



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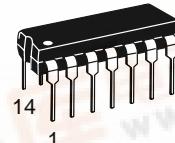
PDIP-8  
P, VP SUFFIX  
CASE 626



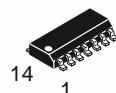
SO-8  
D, VD SUFFIX  
CASE 751



Micro-8  
DM SUFFIX  
CASE 846A



PDIP-14  
P, VP SUFFIX  
CASE 646



SO-14  
D, VD SUFFIX  
CASE 751A



TSSOP-14  
DTB SUFFIX  
CASE 948G

#### ORDERING INFORMATION

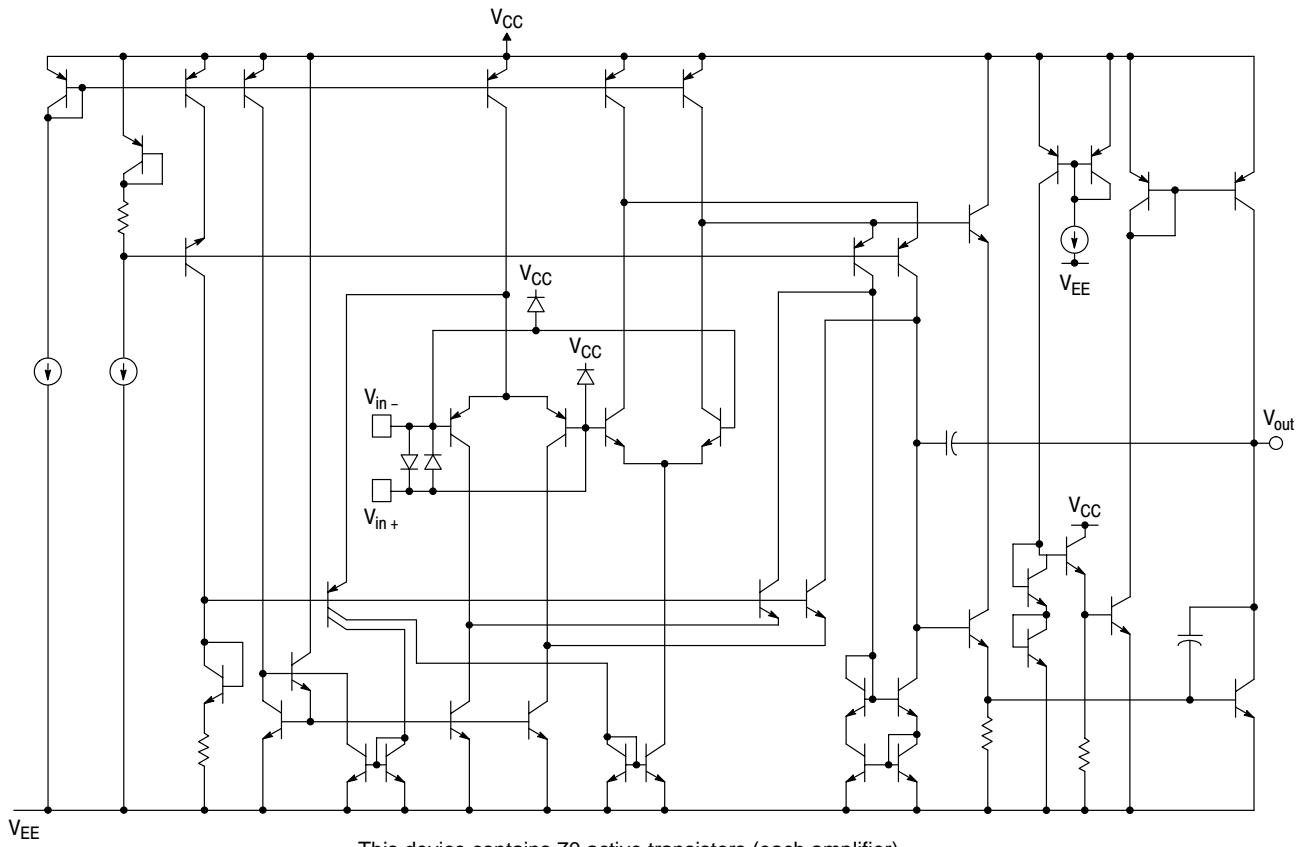
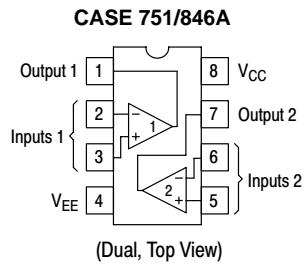
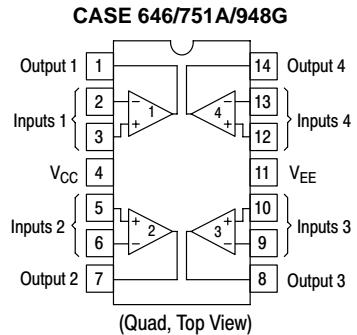
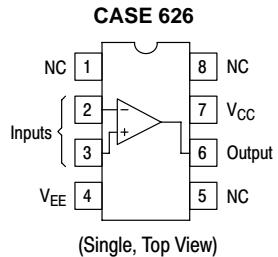
See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

#### DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 11 of this data sheet.

# MC33201, MC33202, MC33204, NCV33202

## PIN CONNECTIONS



**Figure 1. Circuit Schematic**  
(Each Amplifier)

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### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage ( $V_{CC}$ to $V_{EE}$ )	$V_S$	+13	V
Input Differential Voltage Range	$V_{IDR}$	Note 1	V
Common Mode Input Voltage Range (Note 2)	$V_{CM}$	$V_{CC} + 0.5$ V to $V_{EE} - 0.5$ V	V
Output Short Circuit Duration	$t_s$	Note 3	sec
Maximum Junction Temperature	$T_J$	+150	°C
Storage Temperature	$T_{stg}$	-65 to +150	°C
Maximum Power Dissipation	$P_D$	Note 3	mW

### DC ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

Characteristic	$V_{CC} = 2.0$ V	$V_{CC} = 3.3$ V	$V_{CC} = 5.0$ V	Unit
Input Offset Voltage $V_{IO}$ (max) MC33201 MC33202, NCV33202 MC33204	$\pm 8.0$ $\pm 10$ $\pm 12$	$\pm 8.0$ $\pm 10$ $\pm 12$	$\pm 6.0$ $\pm 8.0$ $\pm 10$	mV
Output Voltage Swing $V_{OH}$ ( $R_L = 10$ kΩ) $V_{OL}$ ( $R_L = 10$ kΩ)	1.9 0.10	3.15 0.15	4.85 0.15	$V_{min}$ $V_{max}$
Power Supply Current per Amplifier ( $I_D$ )	1.125	1.125	1.125	mA

Specifications at  $V_{CC} = 3.3$  V are guaranteed by the 2.0 V and 5.0 V tests.  $V_{EE} = \text{Gnd}$ .

### DC ELECTRICAL CHARACTERISTICS ( $V_{CC} = +5.0$ V, $V_{EE} = \text{Ground}$ , $T_A = 25^\circ\text{C}$ , unless otherwise noted.)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ( $V_{CM} = 0$ V to 0.5 V, $V_{CM} = 1.0$ V to 5.0 V) MC33201: $T_A = +25^\circ\text{C}$ MC33201: $T_A = -40^\circ$ to $+105^\circ\text{C}$ MC33201V: $T_A = -55^\circ$ to $+125^\circ\text{C}$ MC33202: $T_A = +25^\circ\text{C}$ MC33202: $T_A = -40^\circ$ to $+105^\circ\text{C}$ MC33202V: $T_A = -55^\circ$ to $+125^\circ\text{C}$ NCV33202V: $T_A = -55^\circ$ to $+125^\circ\text{C}$ (Note 4) MC33204: $T_A = +25^\circ\text{C}$ MC33204: $T_A = -40^\circ$ to $+105^\circ\text{C}$ MC33204V: $T_A = -55^\circ$ to $+125^\circ\text{C}$	3	$ V_{IO} $	—	—	6.0 9.0 13 8.0 11 14 14 10 13 17	mV
Input Offset Voltage Temperature Coefficient ( $R_S = 50$ Ω) $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	4	$\Delta V_{IO}/\Delta T$	— —	2.0 2.0	— —	$\mu\text{V}/^\circ\text{C}$
Input Bias Current ( $V_{CM} = 0$ V to 0.5 V, $V_{CM} = 1.0$ V to 5.0 V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	5, 6	$ I_{IB} $	— — —	80 100 —	200 250 500	nA
Input Offset Current ( $V_{CM} = 0$ V to 0.5 V, $V_{CM} = 1.0$ V to 5.0 V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	—	$ I_{IO} $	— — —	5.0 10 —	50 100 200	nA
Common Mode Input Voltage Range	—	$V_{ICR}$	$V_{EE}$	—	$V_{CC}$	V

- The differential input voltage of each amplifier is limited by two internal parallel back-to-back diodes. For additional differential input voltage range, use current limiting resistors in series with the input pins.
- The input common mode voltage range is limited by internal diodes connected from the inputs to both supply rails. Therefore, the voltage on either input must not exceed either supply rail by more than 500 mV.
- Power dissipation must be considered to ensure maximum junction temperature ( $T_J$ ) is not exceeded. (See Figure 2)
- NCV prefix is for automotive and other applications requiring site and change control.



## MC33201, MC33202, MC33204, NCV33202

**DC ELECTRICAL CHARACTERISTICS (cont.)** ( $V_{CC} = + 5.0$  V,  $V_{EE}$  = Ground,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.)

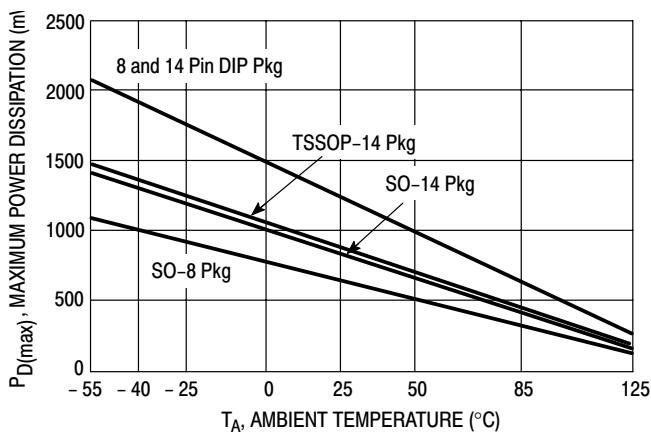
Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Large Signal Voltage Gain ( $V_{CC} = + 5.0$ V, $V_{EE} = - 5.0$ V) $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$	7	$A_{VOL}$	50 25	300 250	— —	kV/V
Output Voltage Swing ( $V_{ID} = \pm 0.2$ V) $R_L = 10 \text{ k}\Omega$ $R_L = 10 \text{ k}\Omega$ $R_L = 600 \Omega$ $R_L = 600 \Omega$	8, 9, 10	$V_{OH}$ $V_{OL}$ $V_{OH}$ $V_{OL}$	4.85 — 4.75 —	4.95 0.05 4.85 0.15	— 0.15 — 0.25	V
Common Mode Rejection ( $V_{in} = 0$ V to 5.0 V)	11	CMR	60	90	—	dB
Power Supply Rejection Ratio $V_{CC}/V_{EE} = 5.0$ V/Gnd to 3.0 V/Gnd	12	PSRR	500	25	—	$\mu\text{V/V}$
Output Short Circuit Current (Source and Sink)	13, 14	$I_{SC}$	50	80	—	mA
Power Supply Current per Amplifier ( $V_O = 0$ V) $T_A = -40^\circ$ to $+105^\circ\text{C}$ $T_A = -55^\circ$ to $+125^\circ\text{C}$	15	$I_D$	— —	0.9 0.9	1.125 1.125	mA

**AC ELECTRICAL CHARACTERISTICS** ( $V_{CC} = + 5.0$  V,  $V_{EE}$  = Ground,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.)

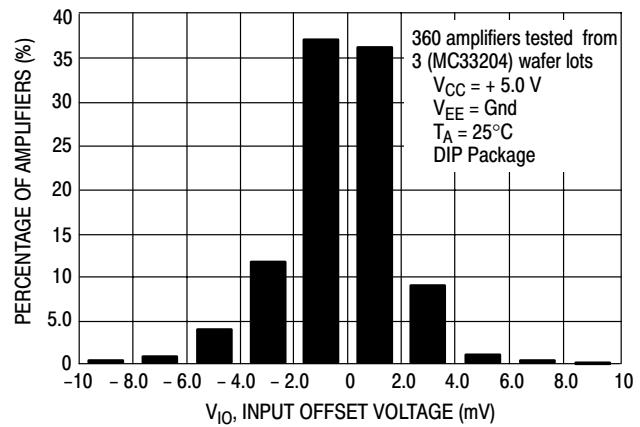
Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Slew Rate ( $V_S = \pm 2.5$ V, $V_O = - 2.0$ V to $+ 2.0$ V, $R_L = 2.0 \text{ k}\Omega$ , $A_V = +1.0$ )	16, 26	SR	0.5	1.0	—	V/ $\mu\text{s}$
Gain Bandwidth Product ( $f = 100$ kHz)	17	GBW	—	2.2	—	MHz
Gain Margin ( $R_L = 600 \Omega$ , $C_L = 0 \text{ pF}$ )	20, 21, 22	$A_M$	—	12	—	dB
Phase Margin ( $R_L = 600 \Omega$ , $C_L = 0 \text{ pF}$ )	20, 21, 22	$\phi_M$	—	65	—	Deg
Channel Separation ( $f = 1.0$ Hz to 20 kHz, $A_V = 100$ )	23	CS	—	90	—	dB
Power Bandwidth ( $V_O = 4.0$ V <sub>pp</sub> , $R_L = 600 \Omega$ , THD $\leq 1\%$ )		BWP	—	28	—	kHz
Total Harmonic Distortion ( $R_L = 600 \Omega$ , $V_O = 1.0$ V <sub>pp</sub> , $A_V = 1.0$ ) $f = 1.0$ kHz $f = 10$ kHz	24	THD	— —	0.002 0.008	—	%
Open Loop Output Impedance ( $V_O = 0$ V, $f = 2.0$ MHz, $A_V = 10$ )		$ Z_O $	—	100	—	$\Omega$
Differential Input Resistance ( $V_{CM} = 0$ V)		$R_{in}$	—	200	—	$\text{k}\Omega$
Differential Input Capacitance ( $V_{CM} = 0$ V)		$C_{in}$	—	8.0	—	pF
Equivalent Input Noise Voltage ( $R_S = 100 \Omega$ ) $f = 10$ Hz $f = 1.0$ kHz	25	$e_n$	— —	25 20	— —	$\text{nV}/\sqrt{\text{Hz}}$
Equivalent Input Noise Current $f = 10$ Hz $f = 1.0$ kHz	25	$i_n$	— —	0.8 0.2	— —	$\text{pA}/\sqrt{\text{Hz}}$



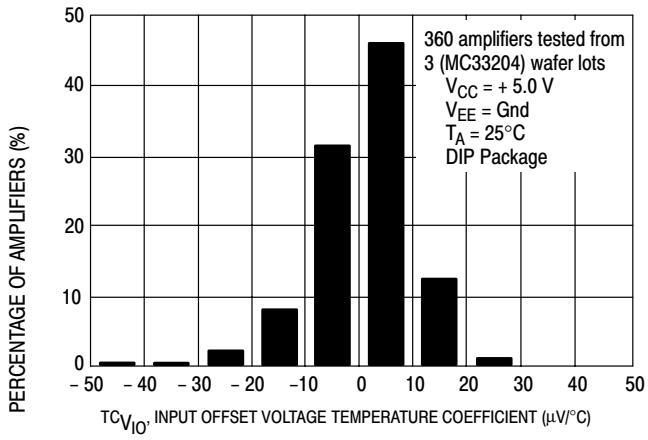
## MC33201, MC33202, MC33204, NCV33202



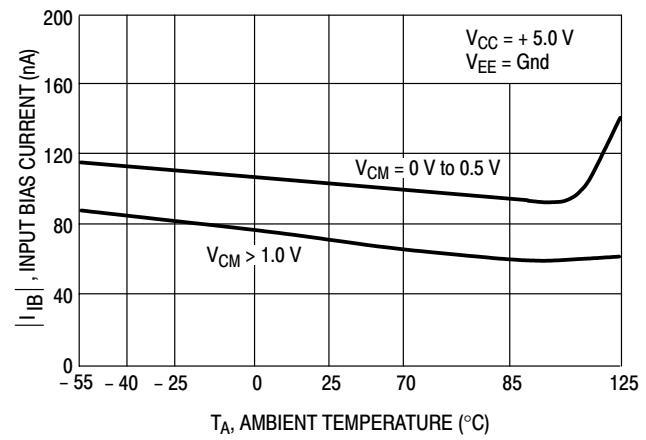
**Figure 2. Maximum Power Dissipation versus Temperature**



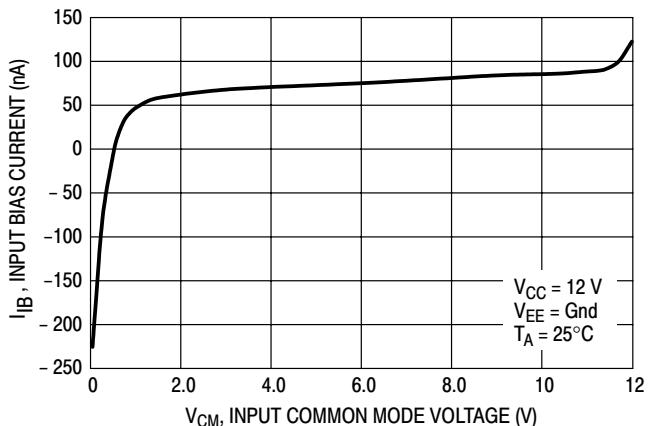
**Figure 3. Input Offset Voltage Distribution**



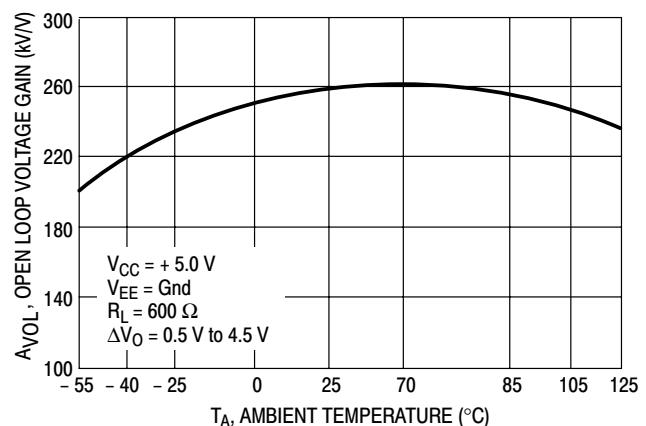
**Figure 4. Input Offset Voltage Temperature Coefficient Distribution**



**Figure 5. Input Bias Current versus Temperature**



**Figure 6. Input Bias Current versus Common Mode Voltage**



**Figure 7. Open Loop Voltage Gain versus Temperature**

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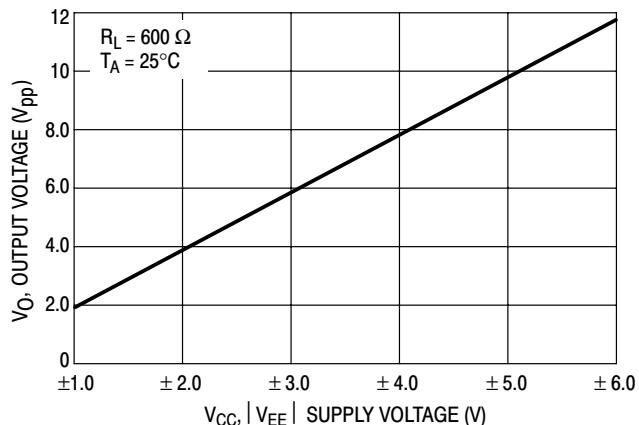


Figure 8. Output Voltage Swing  
versus Supply Voltage

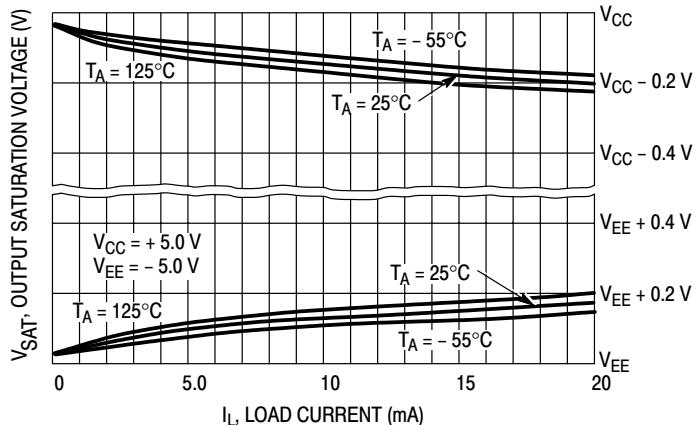


Figure 9. Output Saturation Voltage  
versus Load Current

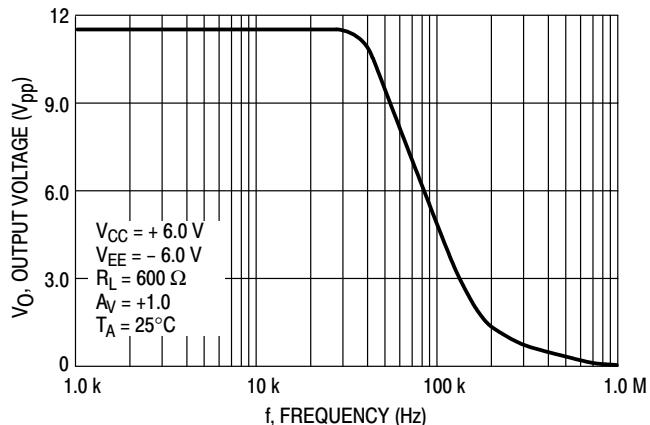


Figure 10. Output Voltage  
versus Frequency

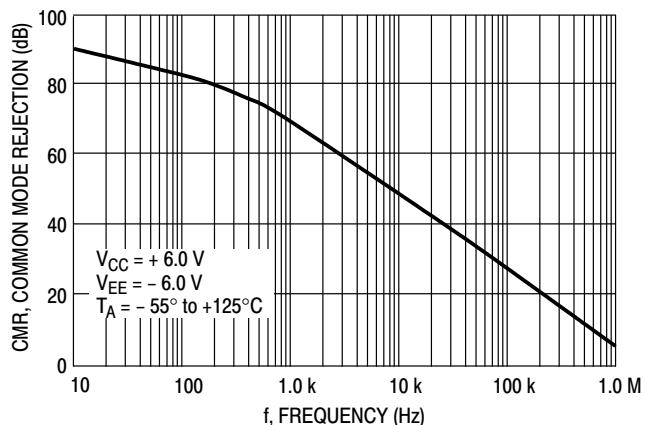


Figure 11. Common Mode Rejection  
versus Frequency

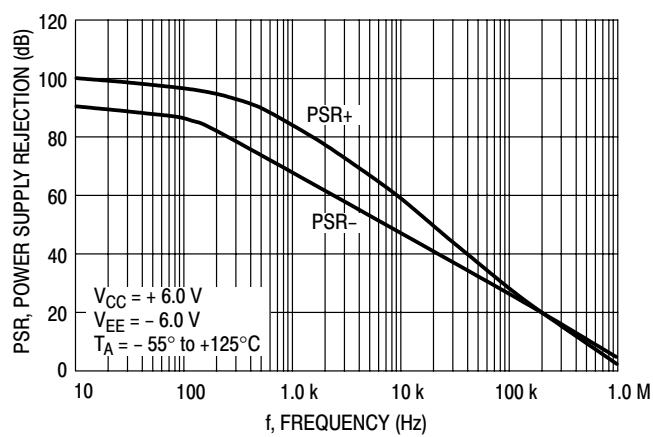


Figure 12. Power Supply Rejection  
versus Frequency

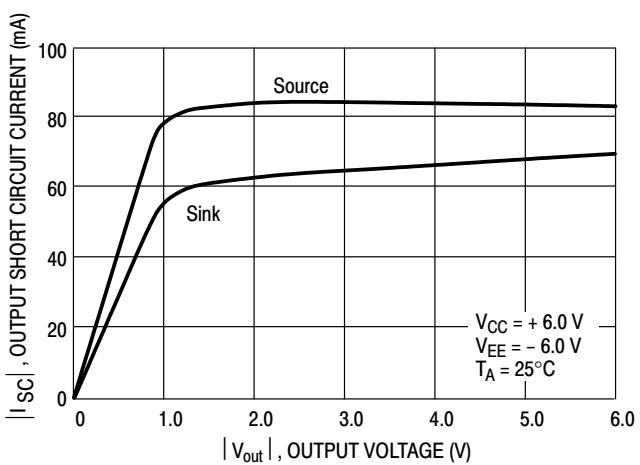
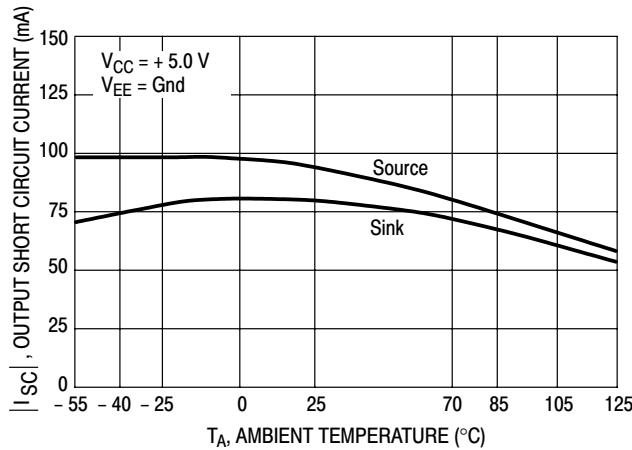
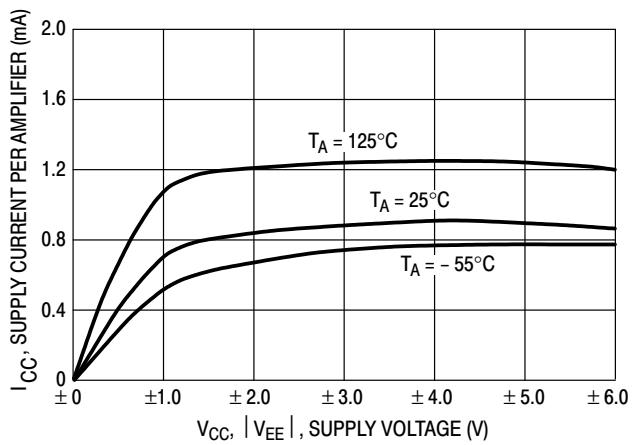


Figure 13. Output Short Circuit Current  
versus Output Voltage

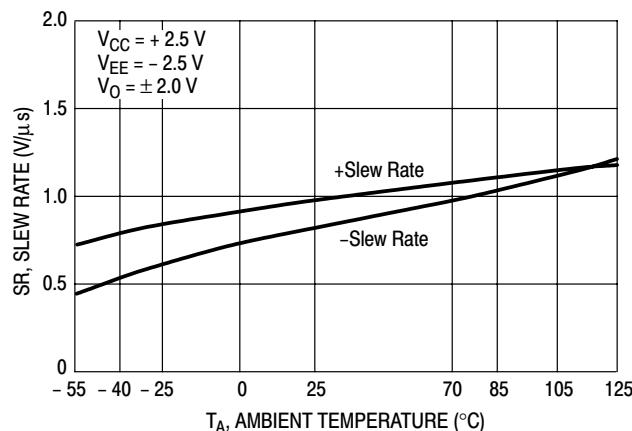
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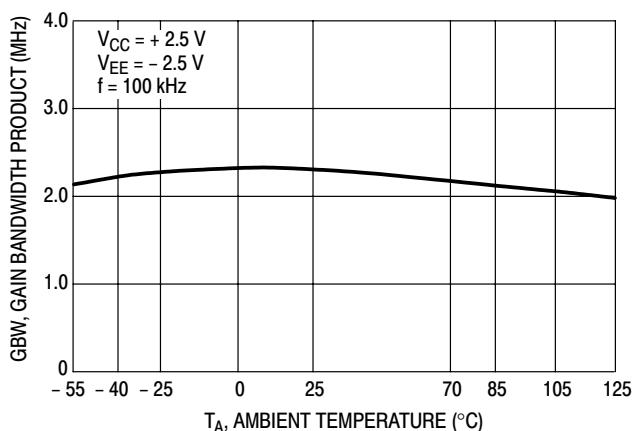
**Figure 14. Output Short Circuit Current versus Temperature**



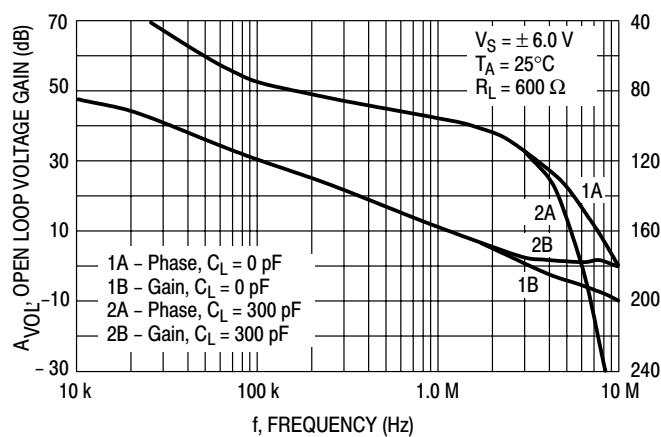
**Figure 15. Supply Current per Amplifier versus Supply Voltage with No Load**



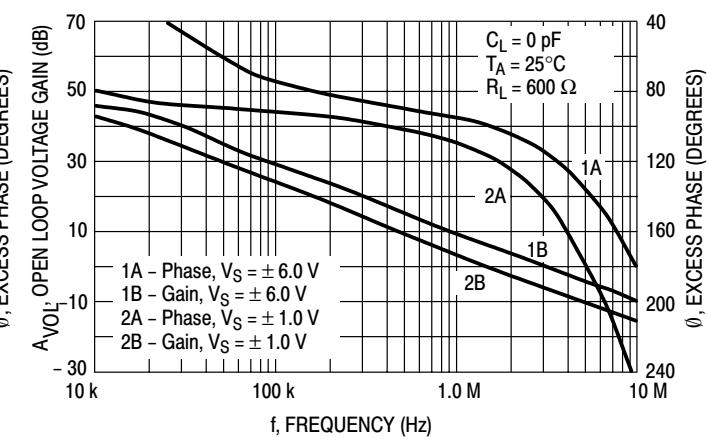
**Figure 16. Slew Rate versus Temperature**



**Figure 17. Gain Bandwidth Product versus Temperature**

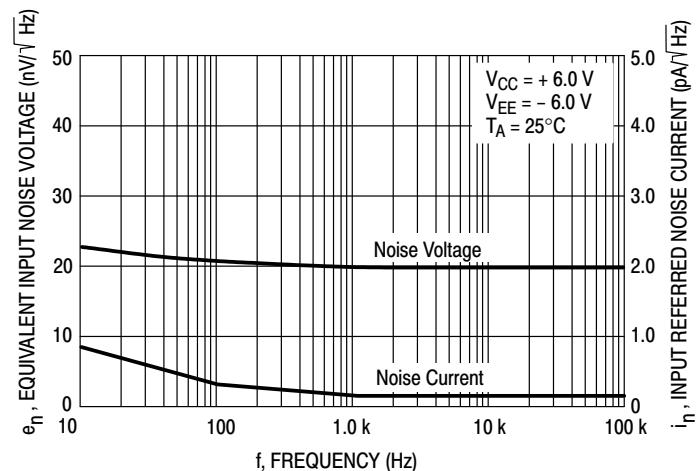
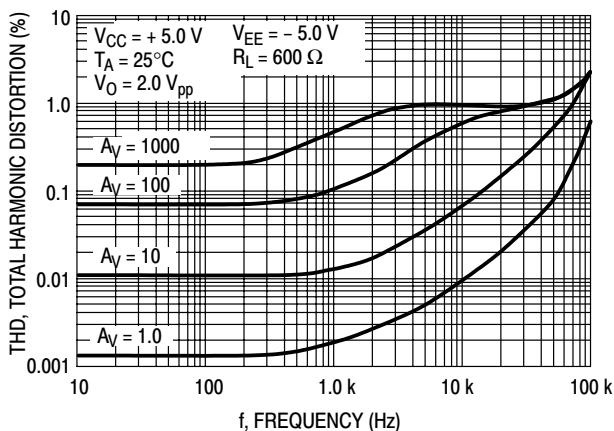
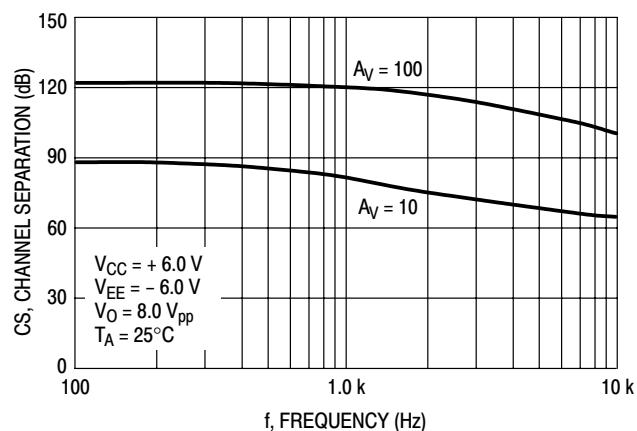
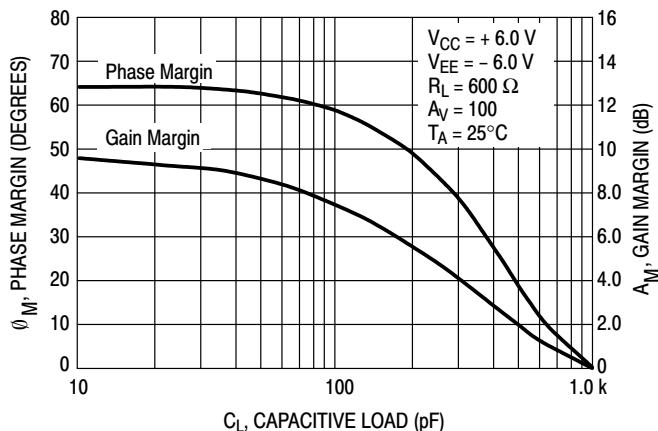
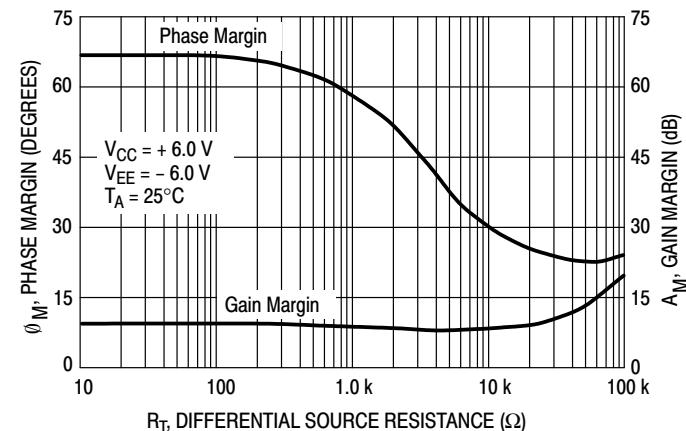
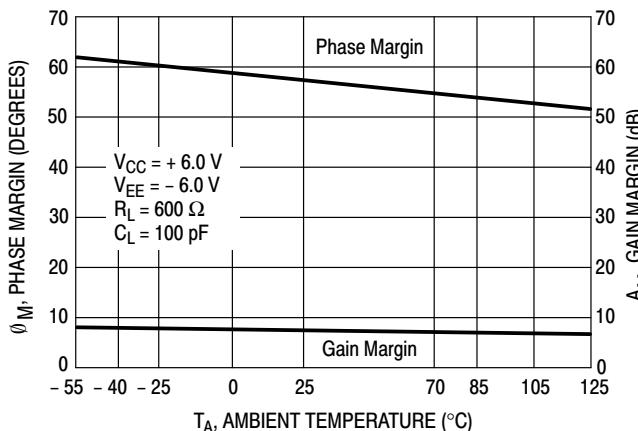


**Figure 18. Voltage Gain and Phase versus Frequency**



**Figure 19. Voltage Gain and Phase versus Frequency**

## MC33201, MC33202, MC33204, NCV33202



## MC33201, MC33202, MC33204, NCV33202

### DETAILED OPERATING DESCRIPTION

#### General Information

The MC33201/2/4 family of operational amplifiers are unique in their ability to swing rail-to-rail on both the input and the output with a completely bipolar design. This offers low noise, high output current capability and a wide common mode input voltage range even with low supply voltages. Operation is guaranteed over an extended temperature range and at supply voltages of 2.0 V, 3.3 V and 5.0 V and ground.

Since the common mode input voltage range extends from  $V_{CC}$  to  $V_{EE}$ , it can be operated with either single or split voltage supplies. The MC33201/2/4 are guaranteed not to latch or phase reverse over the entire common mode range, however, the inputs should not be allowed to exceed maximum ratings.

#### Circuit Information

Rail-to-rail performance is achieved at the input of the amplifiers by using parallel NPN-PNP differential input stages. When the inputs are within 800 mV of the negative rail, the PNP stage is on. When the inputs are more than 800 mV greater than  $V_{EE}$ , the NPN stage is on. This switching of input pairs will cause a reversal of input bias currents (see Figure 6). Also, slight differences in offset voltage may be noted between the NPN and PNP pairs. Cross-coupling techniques have been used to keep this change to a minimum.

In addition to its rail-to-rail performance, the output stage is current boosted to provide 80 mA of output current, enabling the op amp to drive 600  $\Omega$  loads. Because of this high output current capability, care should be taken not to exceed the 150°C maximum junction temperature.

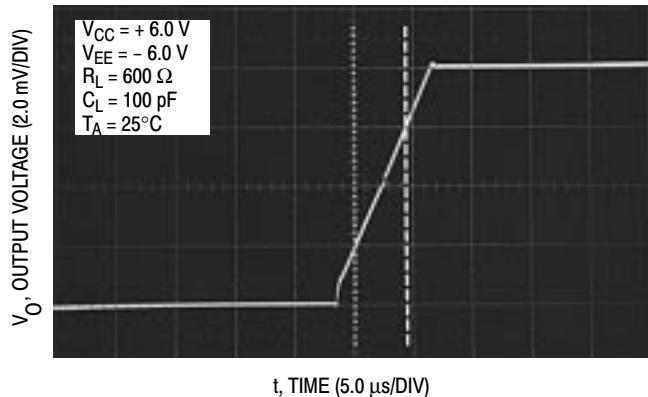


Figure 26. Noninverting Amplifier Slew Rate

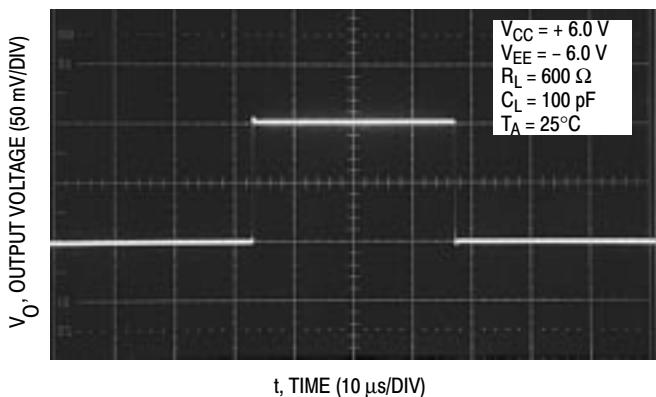


Figure 27. Small Signal Transient Response

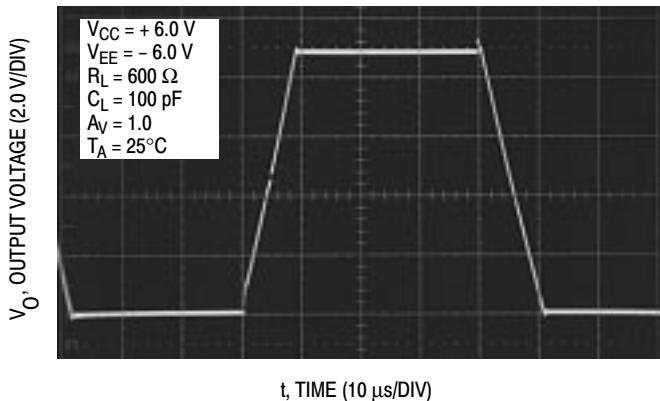


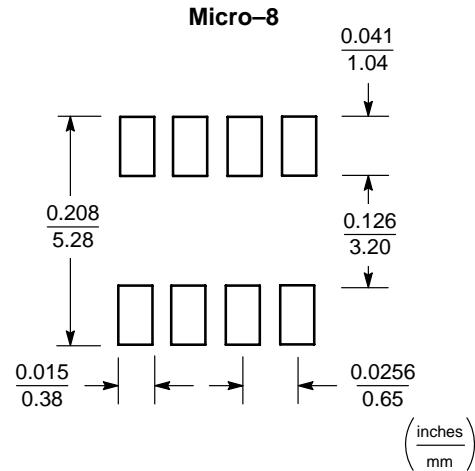
Figure 28. Large Signal Transient Response

## MC33201, MC33202, MC33204, NCV33202

### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to ensure proper solder connection interface

between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process.



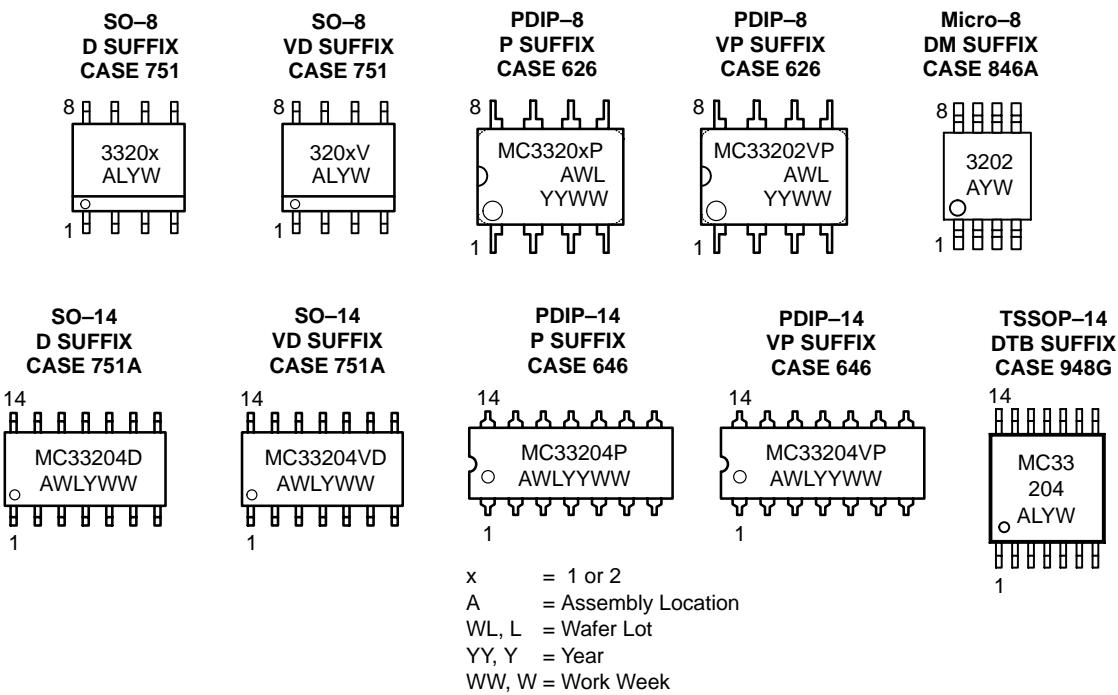
## MC33201, MC33202, MC33204, NCV33202

### ORDERING INFORMATION

Operational Amplifier Function	Device	Operating Temperature Range	Package	Shipping
Single	MC33201D	$T_A = -40^\circ \text{ to } +105^\circ\text{C}$	SO-8	98 Units / Rail
	MC33201DR2		SO-8	2500 Units / Tape & Reel
	MC33201P		Plastic DIP	50 Units / Rail
	MC33201VD	$T_A = -55^\circ \text{ to } 125^\circ\text{C}$	SO-8	98 Units / Rail
Dual	MC33202D	$T_A = -40^\circ \text{ to } +105^\circ\text{C}$	SO-8	98 Units / Rail
	MC33202DR2		SO-8	2500 Units / Tape & Reel
	MC33202DMR2		Micro-8	4000 Units / Tape & Reel
	MC33202P		Plastic DIP	50 Units / Rail
	MC33202VD	$T_A = -55^\circ \text{ to } 125^\circ\text{C}$	SO-8	98 Units / Rail
	MC33202VDR2		SO-8	2500 Units / Tape & Reel
	NCV33202VDR2*		SO-8	2500 Units / Tape & Reel
	MC33202VP		Plastic DIP	50 Units / Rail
Quad	MC33204D	$T_A = -40^\circ \text{ to } +105^\circ\text{C}$	SO-14	55 Units / Rail
	MC33204DR2		SO-14	2500 Units / Tape & Reel
	MC33204DTB		TSSOP-14	96 Units / Rail
	MC33204DTBR2		TSSOP-14	2500 Units / Tape & Reel
	MC33204P	$T_A = -55^\circ \text{ to } 125^\circ\text{C}$	Plastic DIP	25 Units / Rail
	MC33204VD		SO-14	55 Units / Rail
	MC33204VDR2		SO-14	2500 Units / Tape & Reel
	MC33204VP		Plastic DIP	25 Units / Rail

\*NCV33202:  $T_{low} = -55^\circ\text{C}$ ,  $T_{high} = +125^\circ\text{C}$ . Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

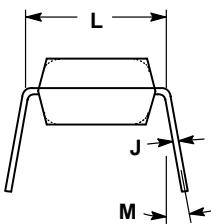
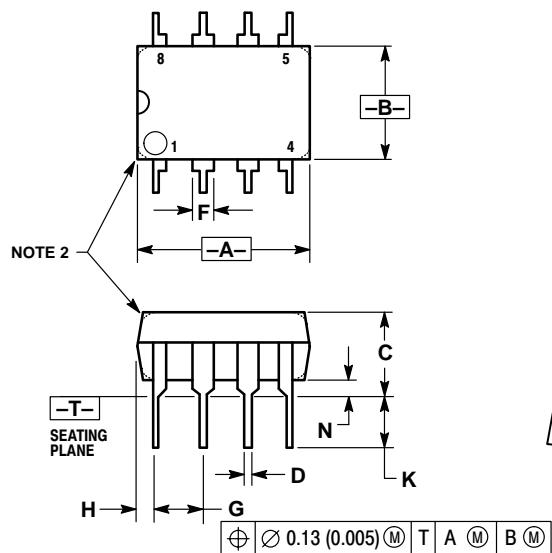
### MARKING DIAGRAMS



# MC33201, MC33202, MC33204, NCV33202

## PACKAGE DIMENSIONS

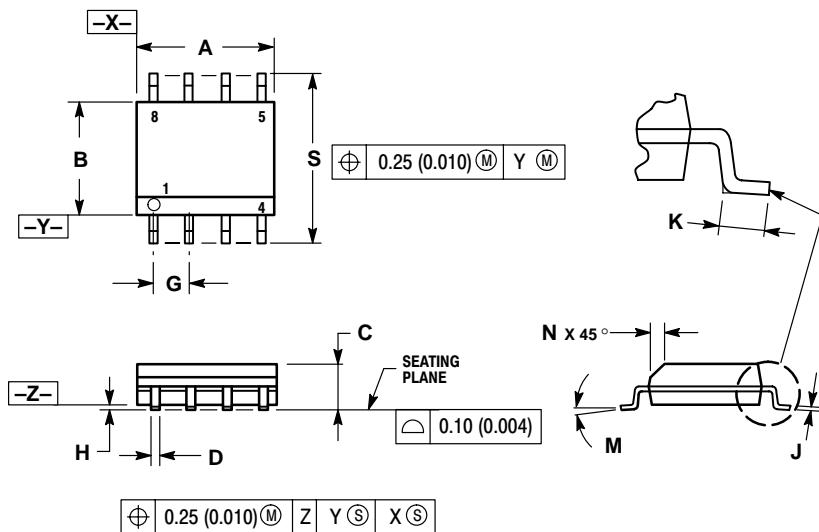
**PDIP-8**  
**P, VP SUFFIX**  
**CASE 626-05**  
**ISSUE L**



- NOTES:
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
  2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
  3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	---	10°
N	0.76	1.01	0.030	0.040

**SO-8**  
**D, VD SUFFIX**  
**CASE 751-07**  
**ISSUE W**



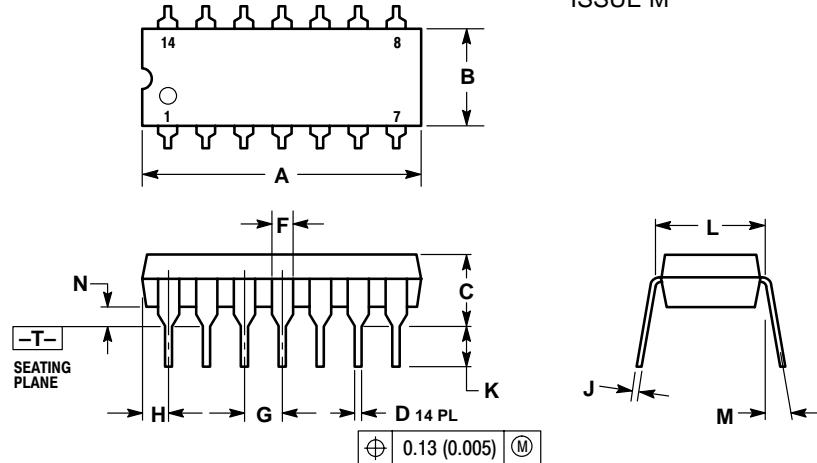
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

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## PACKAGE DIMENSIONS

**PDIP-14**  
**P, VP SUFFIX**  
**CASE 646-06**  
**ISSUE M**

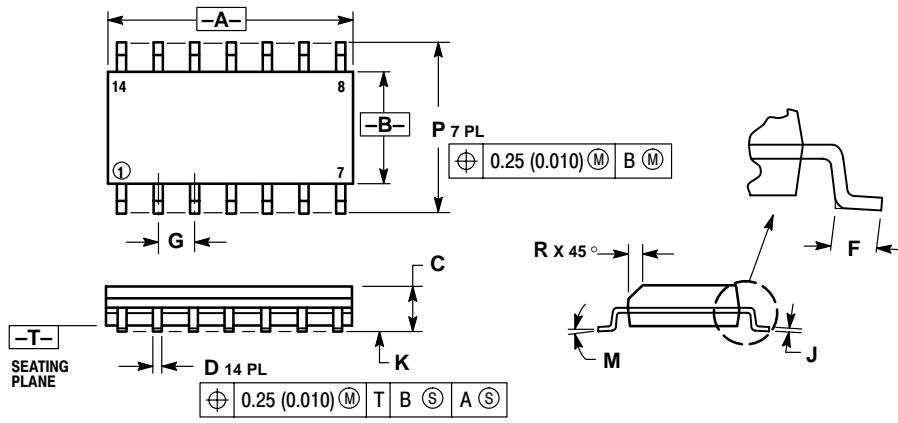


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION B TO CENTER OF LEADS WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	---	10°	---	10°
N	0.015	0.039	0.38	1.01

**SO-14**  
**D, VD SUFFIX**  
**CASE 751A-03**  
**ISSUE F**



**NOTES:**

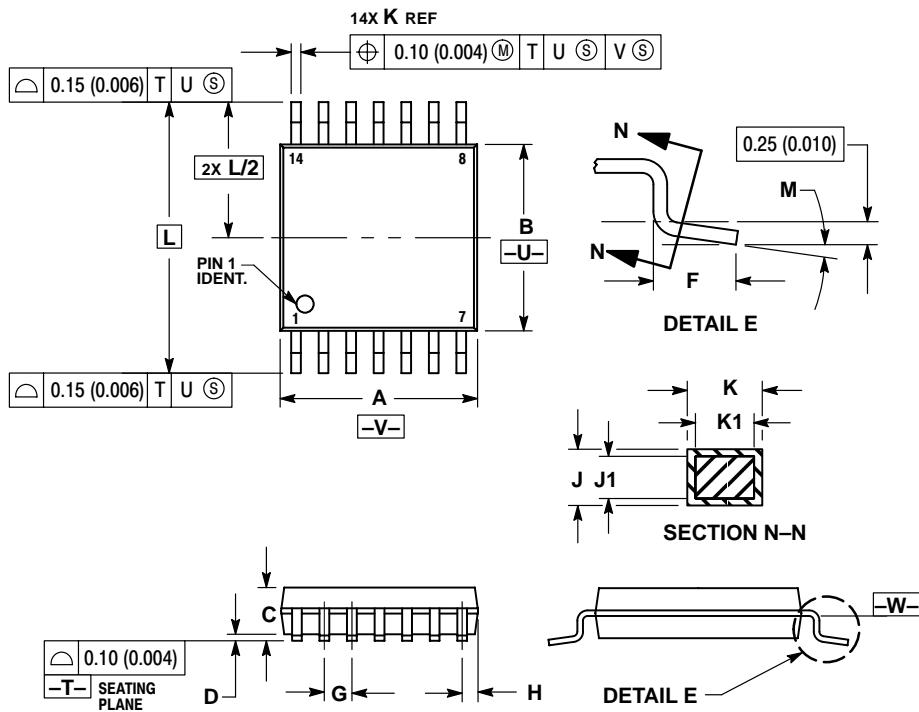
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0 °	7 °	0 °	7 °
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

# MC33201, MC33202, MC33204, NCV33202

## PACKAGE DIMENSIONS

**TSSOP-14  
DTB SUFFIX  
CASE 948G-01  
ISSUE O**



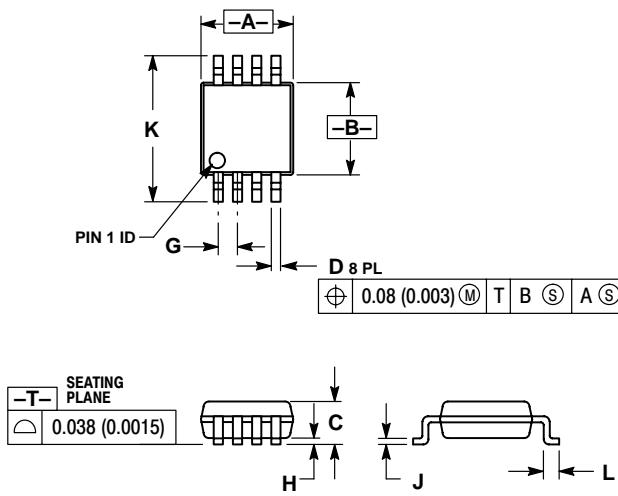
- NOTES:**
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
  5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
  6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
  7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

# MC33201, MC33202, MC33204, NCV33202

## PACKAGE DIMENSIONS

**Micro-8  
DM SUFFIX  
CASE 846A-02  
ISSUE E**



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	---	1.10	---	0.043
D	0.25	0.40	0.010	0.016
G	0.65 BSC		0.026 BSC	
H	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

## MC33201, MC33202, MC33204, NCV33202

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